

HALF-LIFE MEASUREMENT OF ISOMERIC STATES IN $A = 25$ AND 26

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The rapid proton capture process (*rp*-process) passing through proton-rich nuclei plays an important role in the nucleosynthesis. However, a possible path of the *rp*-process $^{24}\text{Al}(p,\gamma)^{25}\text{Si}(p,\gamma)^{26}\text{P}(p,\gamma)^{27}\text{S}$ has not been well studied yet due to lack of experimental data for their nuclear structure. Since the temperature in the hydrogen burning is around 10^9 K (≈ 100 keV), low-lying excited states can affect the *rp*-process taking into account the Maxwell-Boltzmann distribution. In the proton drip-line nucleus ^{26}P , we have recently observed an isomeric state at $E_x = 164$ keV. Then, the first excited state at $E_x = 40(5)$ keV in ^{25}Si , which is also a candidate for the isomer, has not been researched yet in detail. In order to measure the half-life of the first excited state in ^{25}Si and ^{26}P , the γ -ray spectroscopy have been performed at NIRS-HIMAC.

A secondary beam including ^{25}Si and ^{26}P was produced by the projectile fragmentation of a 300-MeV/u primary beam of ^{28}Si on a 20-mm-thick CH_2 target. The secondary beam was separated and identified by using SB2 beamline and was implanted in an active stopper consisting of three plastic scintillators. The γ rays were measured with three kinds of detectors surrounding the stopper, four $\text{LaBr}_3(\text{Ce})$ detectors, a HPGe detector, and a $\text{NaI}(\text{Tl})$ detector. The delayed γ rays of 44.2(1) keV have been observed in ^{25}Si by these detectors. By fitting the γ -gated decay curve, the half-life has been determined to be 43(1) ns for the first time. In addition, the half-life of isomeric state in ^{26}P has been also determined to be $T_{1/2} = 104(3)$ ns.

The transition probability deduced from the γ -ray energy and the half-life suggests M1(E2) multipolarity with Weisskopf estimation for $^{25}\text{Si}(^{26}\text{P})$. We will present the spin assignment, the estimation of the (*p*, γ) reaction rate, and the Coulomb energy difference by comparing with the Shell model and the mirror nucleus.